Anti-damping spin transfer torque through epitaxial nickel oxide
Takahiro Moriyama, So Takei, Masaki Nagata, Yoko Yoshimura, Noriko Matsuzaki, Takahito Terashima, Yaroslav Tserkovnyak, and Teruo Ono

View online: http://dx.doi.org/10.1063/1.4918990
View Table of Contents: http://scitation.aip.org/content/aip/journal/apl/106/16?ver=pdfcov
Published by the AIP Publishing

Articles you may be interested in
Localized excitation of magnetostatic surface spin waves in yttrium iron garnet by shorted coaxial probe detected via spin pumping and rectification effect

Quantification of the spin-Hall anti-damping torque with a resonance spectrometer

Determination of intrinsic spin Hall angle in Pt

Thickness dependence of spin torque ferromagnetic resonance in Co75Fe25/Pt bilayer films

Spin transport parameters in metallic multilayers determined by ferromagnetic resonance measurements of spin-pumping
J. Appl. Phys. 113, 153906 (2013); 10.1063/1.4801799
Anti-damping spin transfer torque through epitaxial nickel oxide

Takahiro Moriyama,1 So Takei,2 Masaki Nagata,1 Yoko Yoshimura,1 Noriko Matsuzaki,1 Takahito Terashima,3 Yaroslav Tserkovnyak,2 and Teruo Ono1

1Institute for Chemical Research, Kyoto University, Uji, Kyoto 611-0011, Japan
2Department of Physics and Astronomy, University of California, Los Angeles, California 90095, USA
3Research Center for Low Temperature and Materials Sciences, Kyoto University, Kyoto 606-8501, Japan

(Received 9 February 2015; accepted 12 April 2015; published online 22 April 2015)

We prepare the high quality epitaxial MgO(001)/Pt(001)/NiO(001)/FeNi/SiO2 films to investigate the spin transport in the NiO antiferromagnetic insulator. The ferromagnetic resonance measurements of the FeNi under a spin current injection from the Pt by the spin Hall effect revealed the change of the ferromagnetic resonance linewidth depending on the amount of the spin current injection. The results can be interpreted that there is an angular momentum transfer through the NiO. A high efficient angular momentum transfer we observed in the epitaxial NiO can be attributed to the well-defined orientation of the antiferromagnetic moments and the spin quantization axis of the injected spin current. © 2015 AIP Publishing LLC.

Since the theoretical predictions1,2 followed by experimental demonstrations,3,4 spin transfer torque (STT) has been an efficient and promising technique to control magnetizations of ferromagnetic materials in modern spintronics devices. This novel technique is based on an interaction between electron spin and local magnetic moments. Namely, the angular momentum of the electron spin is transferred to and exerts a torque on the magnetization. The same interaction should be conserved in antiferromagnets (AFMs), in which there are microscopic local magnetic moments that compensate each other to exhibit no net magnetization.5–8 As AFMs have been abandoned as an active material in spintronics in spite of their potential applications in the THz regime,9 it is of great interest to investigate the STT in AFMs.

Despite numerous theoretical works on STT in AFMs, there are only a few experiments indicating the possibilities of interactions between the electron spin and the AFM moments.10–13 The most recent investigations of spin transport in AFM materials have raised an interesting question, whether AFMs can be transparent to the angular momentum flow.12,13 Wang et al.13 performed spin pumping measurements on Y3Fe5O12/NiO/Pt, and a spin voltage signal was detected by the inverse spin Hall effect in Pt. Spin transfer in a metallic AFM system with a Pt/IrMn/FeCoB heterostructure has also been investigated by our group by means of the spin-torque ferromagnetic resonance (ST-FMR).12

In this letter, we prepared MgO(001) substrate/Pt/NiO/FeNi/SiO2 multilayers, in which the films are epitaxially grown until the NiO layer, and performed a ST-FMR measurement to quantify the anti-damping spin torque transported between the Pt and the FeNi through the NiO layer. In order to investigate the spin torque in NiO, we created and injected a pure spin current by the spin Hall effect in Pt. The schematic layer structure of the injection scheme is shown in Fig. 1(b). The electron flowing in the Pt layer experiences a spin dependent scattering due to spin-orbit interaction, resulting in the opposite flow of spin polarized electrons orthogonal to the electron flow.14 This spin current is a so-called pure spin current, which does not involve charge current flow. This spin current induces a spin accumulation at the Pt/NiO interface and exerts a spin torque on the NiO magnetic moments in a similar manner to the Pt/ferromagnetic insulator case.15 We investigate the magnetic damping

FIG. 1. (a) Crystal lattice of NiO. Green and red spheres indicate the Ni and O atoms, respectively. Magnetic moments reside at the Ni atoms. (b) Schematic illustration of the spin injection scheme. The bottom Pt layer invokes an injection of the pure spin current due to the spin Hall effect. (c) Reflection high energy electron diffraction images for the Pt surface (i) and the NiO surface (ii). Schematic of the crystal orientation relationship is shown in (iii).
of the FeNi grown on top of the NiO under the pure spin current injection to understand the STT in the NiO layer. Unlike ferromagnetic materials, magnetic moments in oxide antiferromagnetic materials cannot be easily controlled by external magnetic field and they are tied with the crystalline magnetic anisotropy.\(^\text{16}\) In order to control the AFM magnetic moments, we develop a single crystal NiO. Nickel oxide has a rock salt structure with the lattice constant of 4.2 Å,\(^\text{17}\) which is similar to the lattice constants of MgO (4.1 Å) and Pt (3.9 Å) within a 5% mismatch. The magnetic moments inhabit the nickel atoms as shown in Fig. 1(a). The magnetic moments in \{111\} planes are ferromagnetically coupled with its anisotropy in the \langle -211\rangle, \langle 1-21\rangle, and \langle 11-2\rangle directions. The antiferromagnetism originates from the antiparallel coupling between the magnetic moments in the neighboring \{111\} planes by super exchange coupling. From the symmetry of these crystal planes, there are twelve possible orientations of magnetic moments, each of which makes a non-collinear angle with the [010] directions.

The layer stacks of Pt 5 nm/NiO 10 nm/FeNi 3 nm/SiO\(_2\) 5 nm were prepared on MgO(001) single crystal substrate (Fig. 1(b)). Pt layer was formed by magnetron sputtering on MgO(001) with a substrate temperature of 600 °C and was then taken out to the air. After transferring the sample to another chamber for pulsed laser deposition (PLD), the sample was heated to 400 °C and its surface crystallinity was checked by reflection high energy electron diffraction (RHEED). Fig. 1(c-i) shows the RHEED pattern of the Pt surface in the direction of MgO(001)[100]. Clear streaks indicate the atomically smooth surface of Pt layer, and the crystal orientation relative to the MgO is determined to be MgO(001)[001]/Pt(001)[001]. NiO layer was then deposited by PLD with an oxygen partial pressure of 2 × 10\(^{-2}\) Pa at the substrate temperature of 400 °C. The RHEED pattern for the surface of NiO 10 nm shown in Fig. 1(c-ii) also shows clear streaks indicating the atomically smooth surface from which we determined the epitaxial orientation relationship between the NiO and the Pt layer to be MgO(001)[100]/Pt(001)[100]/NiO(001)[100]. The following FeNi and SiO\(_2\) layers were deposited by magnetron sputtering. The samples shown in this letter are as-deposited with no unidirectional anisotropy in FeNi. Control samples of MgO(001)/Pt 5 nm/SiO\(_2\) 10 nm/FeNi 3 nm/SiO\(_2\) 5 nm and MgO(001)/Pt 5 nm/FeNi 3 nm/SiO\(_2\) 5 nm, all made by magnetron sputtering, were grown epitaxially up to the Pt layer.

In order to investigate the spin transport in the NiO, we performed the ST-FMR measurement, which is a useful method for quantifying the spin torque exerting in the system. The film is patterned into 4–10 μm wide strips attached to a coplanar waveguide facilitating both the r.f. and d.c. current injection into the strip. The long axis of the strip along which the d.c. current flows is parallel to [100] direction of the MgO substrate. This ensures the spin quantization axis of the pure spin current to be in the [010] direction, thus always making a finite angle with the anisotropic magnetic moments of the epitaxially grown NiO, and so that the spin current would exert a spin torque on the NiO magnetic moments. ST-FMR is performed by sweeping the external magnetic field at a fixed frequency of the r.f. current. Figure 2(a) shows the measurement configuration together with our coordinate system. The positive electric current is defined when it flows along the positive \(x\) direction. The external positive magnetic field is applied in the sample plane and at 45° away from \(x\) axis. We apply nominal r.f. power up to 14 dBm and d.c. current up to 2.5 mA to the strip. All the measurements were performed at room temperature. The expected FMR spectra with the spin injection by the spin Hall effect in such a system can be composed of symmetric and antisymmetric Lorentzians. The detailed explanation can be found elsewhere.\(^\text{12,18}\) The obtained spectra shown in Fig. 2(b) for the Pt/NiO/FeNi/SiO\(_2\) are composed of both Lorentzians and the ratio between the symmetric and antisymmetric components is found to be finite, implying that the spin torque is exerted on the FeNi layer through the NiO. In order to further characterize the spin torque in the NiO layer, we mainly focused on the change in the linewidth under the spin current injection which reflects the change in effective damping due to the anti-damping spin torque due to the spin current.

Figure 3 summarizes the results obtained by the ST-FMR measurement and compares with the control samples. The most important results in this letter on the linewidth change due to the spin current are shown in Figs. 3(g)–3(i). Before discussing our central results, we would like to first show the basic FMR results obtained by the ST-FMR measurement. The ferromagnetic resonance for three different samples summarized in Figs. 3(a)–3(c) are well fitted by Kittel’s formula

\[
\nu = \frac{1}{2\pi} \sqrt{(H_{ex} + H_d)(H_{ex} + H_d + 4\pi M_{s,f})},
\]

where \(\gamma = 1.76 \times 10^{11} (\text{s}^{-1} \text{T}^{-1})\) is gyromagnetic ratio, \(H_{ex}\) is the external magnetic field, \(H_d\) is the in-plane anisotropy field, and \(4\pi M_{s,f}\) is the effective demagnetizing field. The fitting yields \(4\pi M_{s,f} = 0.59, 0.72, \) and 0.6 T with a negligible in-plane anisotropy for Pt/NiO 10 nm/FeNi, Pt/FeNi, and Pr/SiO\(_2\)/FeNi samples, respectively. We separately measured the saturation magnetization \(M_s = 0.78\ T\) for a single layer of the FeNi by SQUID magnetometry. The discrepancy between the saturation magnetization and the \(4\pi M_{s,f}\) values may originate from the perpendicular anisotropy or magnetic dead layer at the interface. The Gilbert damping \(\alpha\) of the FeNi is extracted...
This article is copyrighted as indicated in the article. Reuse of AIP content is subject to the terms at: http://scitation.aip.org/termsconditions. Downloaded to IP: 130.54.110.71 On: Thu, 30 Jul 2015 01:36:20

from the linewidth $\Delta H$ as a function of frequency by

$$
\Delta H = \Delta H_0 + 2\pi f x / \gamma
$$

where $\Delta H_0$ is the inhomogeneous broadening.\(^{19}\) We obtain $x = 0.016$, 0.04, and 0.009 and $\Delta H_0 = 14$, 16, and 6 Oe for Pt/NiO 10 nm/FeNi, Pt/FeNi, and Pt/SiO$_2$/FeNi, respectively, as the actual fittings are shown in Figs. 3(d)–3(f). Finally, the most important observations on the change of the linewidth by the spin current are shown in Figs. 3(g)–3(i). It is clearly seen that the change in the linewidth is observed in the Pt/NiO/FeNi sample as well as the Pt/FeNi sample and not in the Pt/SiO$_2$/FeNi sample. As explained above, the d.c. current flowing in the Pt layer invokes the spin Hall effect and induces a spin accumulation at the Pt/NiO interface. The spin torque transferred into the ferromagnetic layer should result in either increase or decrease in the linewidth as the typical Pt/FeNi linewidth change can be seen in Fig. 3(h). With the positive spin Hall angle and the positive external field, the magnetization in FeNi feels the anti-damping torque in the positive d.c. current, leading to the decrease of the FMR linewidth.\(^{18}\) On the other hand, by flipping the magnetization direction with the negative external field, the positive d.c. current results in the increase of the linewidth. As the ST-FMR measurement is only sensitive to the linewidth (i.e., damping) of the FeNi layer, the change in the linewidth in Pt/NiO/FeNi can be interpreted in the way that the angular momentum is indeed transferred through the NiO.\(^{15}\) No linewidth change in the Pt/SiO$_2$/FeNi sample indicates that the angular momentum transport is completely impeded by non-magnetic SiO$_2$ layer as one expects.

The relation between the linewidth and the injected spin current is given by

$$
\delta H / I_{dc} = \frac{1}{\sqrt{2}} \frac{2\pi f}{\gamma} (H_{ex} + 2\pi M_{eff}) M_{FM} w^2 \frac{e}{h} \left( \beta_{SH/FeNi} \right) (r_{FeNi}),
$$

where $\delta H$ is the change in linewidth, $H_{ex}$ is the external field, $h$ is the Planck’s constant, $e$ is the elementary charge, $w$ is the width of the strip, $M_{FM}$ is the thickness of FeNi, $\beta_{SH/FeNi}$ is the spin Hall angle of the Pt, $r_{FeNi}$ is the shunt current ratio of the Pt layer, and $r_{Pt}$ is the thickness. Here, we introduce $\beta (0 \leq \beta \leq 1)$ as the spin-transfer efficiency in the NiO layer. $\beta = 1$ when all of the injected spin current exerts a spin torque on the FeNi layer through the NiO layer (and also corresponding to the limit of zero NiO thickness), and $\beta = 0$ when it is dissipated before reaching to the FeNi layer. Using the effective spin Hall angle $\beta_{SH/FeNi}$ for the Pt/FeNi interface for both Pt/FeNi and Pt/NiO interfaces and the same shunt current ratios in Pt for both Pt/NiO/FeNi and Pt/FeNi samples, we can simply compare $\delta H / I_{dc}$ values obtained from the slope of the plots in Figs. 3(g) and 3(h) to see how the NiO efficiently carries the spin angular momentum. By fitting with the data in Figs. 3(g) and 3(h), we obtained $\delta H / I_{dc}$ to be $1.1 \pm 0.1$ and $1.2 \pm 0.1$ Oe/mA, respectively, for Pt/NiO/FeNi and Pt/FeNi samples. These results yield a highly efficient spin transport with $\beta = 0.82$ for the 10 nm NiO layer comparing with the previous report.\(^{13}\)

At finite temperatures, spin transport through NiO can be transported by the coherent Neel order dynamics as well as incoherent thermal magnons. While the incoherent contribution is expected to decay exponentially over the spin diffusion length $\lambda_{sd}$, the coherent contribution should decay
exponentially over the so-called healing length $\lambda_h$ (determined by various magnetic anisotropies in NiO). The experimental value $\lambda_s$ for the exponential decay length should be determined by $\lambda_s \equiv \max\{\lambda_{sd}, \lambda_h\}$. Both theoretical and experimental study of the temperature-dependence of the linewidth is still lacking but interesting. A study of the linewidth at lower temperatures will effectively freeze out the thermal magnons allowing one to quantify spin transport mediated purely by the coherent Neel dynamics, and the results for the linewidth as a function of NiO thickness at these low temperatures can be used to extract the AFM healing length.

A theory for spin transport through AFM insulators mediated by coherent Neel order dynamics (i.e., thermal contribution neglected) was developed in Refs. 7 and 20; such a theory is sufficient either at temperatures well below the Neel temperature (at which thermal magnon density is negligible) or for $\lambda_{sd} \ll \lambda_h$. Reference 20 studies the effects of coherent spin propagation through the AFM on the FMR linewidth in a metal|AFM|ferromagnet trilayer (akin to the current experiment) assuming an AFM with easy-axis anisotropy and the dc FMR field aligned parallel to the easy-axis. However, NiO is known to have a strong magnetic easy-plane parallel to the (111) plane, within which a much weaker easy-axis exists,21 and the assumption of parallel alignment between the dc FMR field and the Neel easy-axis may be inapplicable to the current experiment. Further theoretical work accounting for the magnetic anisotropies and the dependences on the relative orientations between the Neel order and the dc FMR field, and further experimental characterization of the Neel vector orientation with respect to the Pt current and dc FMR field directions are clearly needed for quantitative comparisons between experiment and theory.

In summary, we performed the ST-FMR measurement on NiO and observed the change of the linewidth as a function of the spin current from the Pt due to the spin Hall effect. Our observation is interpreted that there is an angular momentum transfer from the Pt to the FeNi through the NiO. Our high efficient angular momentum transfer in the NiO comparing with the previous report on disordered NiO indicates that the orientation of the AFM moments is important, which presumably support the available theoretical model assuming the angular momentum transfer mediated by AFM spin fluctuations. Our results also assure that the NiO antiferromagnetic moments are interacting with the spin current and exciting dynamics. It would be of great interest to experimentally prove the spin torque magnetic excitation in antiferromagnet as the similar concept has already been demonstrated in ferromagnetic thin films.22

This work was partly supported by Grants-in-Aid for Scientific Research (S), Grant-in-Aid for Young Scientists (B) from Japan Society for the Promotion of Science. S.T. and Y.T. would like to acknowledge support by FAME (an SRC STARnet center sponsored by MARCO and DARPA).

---